

MMSZ5221ET1 Series

Preferred Device

Zener Voltage Regulators

500 mW SOD-123 Surface Mount

Three complete series of Zener diodes are offered in the convenient, surface mount plastic SOD-123 package. These devices provide a convenient alternative to the leadless 34-package style.

Features

- Pb-Free Packages are Available
- 500 mW Rating on FR-4 or FR-5 Board
- Wide Zener Reverse Voltage Range – 2.4 V to 110 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- General Purpose, Medium Current
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Peak Power – 225 W (8 x 20 μs)

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic case

FINISH: Corrosion resistant finish, easily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by polarity band

FLAMMABILITY RATING: UL 94 V-0

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Power Dissipation @ 20 μs (Note 1) @ $T_L \leq 25^\circ\text{C}$	P_{pk}	225	W
Total Power Dissipation on FR-5 Board, (Note 2) @ $T_L = 75^\circ\text{C}$ Derated above 75°C	P_D	500 6.7	mW mW/°C
Thermal Resistance, (Note 3) Junction-to-Ambient	$R_{\theta JA}$	340	°C/W
Thermal Resistance, (Note 3) Junction-to-Lead	$R_{\theta JL}$	150	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	°C

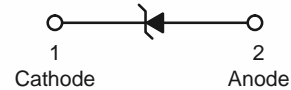
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 11.
2. FR-5 = 3.5 x 1.5 inches, using the minimum recommended footprint.
3. Thermal Resistance measurement obtained via infrared Scan Method.



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SOD-123
CASE 425
STYLE 1

MARKING DIAGRAM



xxx = Specific Device Code
M = Date Code

ORDERING INFORMATION

Device**	Package	Shipping†
MMSZ52xxET1	SOD-123	3000/Tape & Reel
MMSZ52xxET1G	SOD-123 (Pb-Free)	3000/Tape & Reel
MMSZ52xxET3	SOD-123	10,000/Tape & Reel
MMSZ52xxET3G	SOD-123 (Pb-Free)	10,000/Tape & Reel

**The "T1" suffix refers to an 8 mm, 7 inch reel.
The "T3" suffix refers to an 8 mm, 13 inch reel.

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

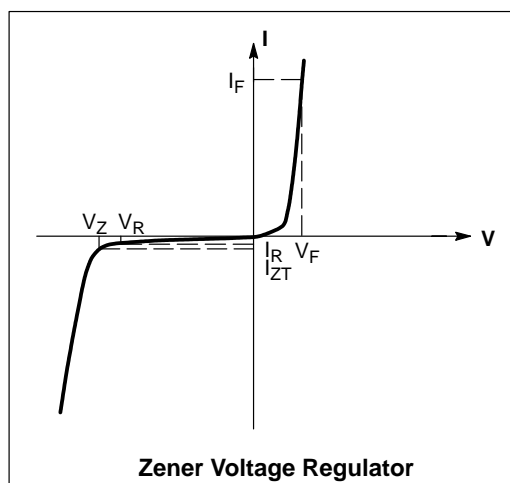
Devices listed in **bold, italic** are ON Semiconductor Preferred devices. Preferred devices are recommended choices for future use and best overall value.



MMSZ5221ET1 Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.95\text{ V Max.}$ @ $I_F = 10\text{ mA}$)

Symbol	Parameter
V_Z	Reverse Zener Voltage @ I_{ZT}
I_{ZT}	Reverse Current
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_{ZK}	Reverse Current
Z_{ZK}	Maximum Zener Impedance @ I_{ZK}
I_R	Reverse Leakage Current @ V_R
V_R	Reverse Voltage
I_F	Forward Current
V_F	Forward Voltage @ I_F



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.9\text{ V Max.}$ @ $I_F = 10\text{ mA}$)

Device	Device Marking	Zener Voltage (Notes 4 and 5)				Zener Impedance (Note 6)			Leakage Current	
		V_Z (V)			@ I_{ZT}	Z_{ZT} @ I_{ZT}	Z_{ZK} @ I_{ZK}		I_R @ V_R	
		Min	Nom	Max	mA	Ω	Ω	mA	μA	V
MMSZ5221ET1	CA1	2.28	2.4	2.52	20	30	1200	0.25	100	1
MMSZ5223ET1	CA3	2.57	2.7	2.84	20	30	1300	0.25	75	1
MMSZ5226ET1	CA6	3.14	3.3	3.47	20	28	1600	0.25	25	1
MMSZ5228ET1	CA8	3.71	3.9	4.10	20	23	1900	0.25	10	1
MMSZ5229ET1	CA9	4.09	4.3	4.52	20	22	2000	0.25	5	1
MMSZ5231ET1	CB2	4.85	5.1	5.36	20	17	1600	0.25	5	2
MMSZ5232ET1, G	CB3	5.32	5.6	5.88	20	11	1600	0.25	5	3
MMSZ5234ET1	CB5	5.89	6.2	6.51	20	7	1000	0.25	5	4
MMSZ5235ET1	CB6	6.46	6.8	7.14	20	5	750	0.25	3	5
MMSZ5236ET1, G	CB7	7.13	7.5	7.88	20	6	500	0.25	3	6
MMSZ5237ET1	CB8	7.79	8.2	8.61	20	8	500	0.25	3	6.5
MMSZ5240ET1, G	CC2	9.50	10	10.50	20	17	600	0.25	3	8
MMSZ5242ET1, G	CC4	11.40	12	12.60	20	30	600	0.25	1	9.1
MMSZ5243ET1	CC5	12.35	13	13.65	9.5	13	600	0.25	0.5	9.9
MMSZ5244ET1	CC6	13.30	14	14.70	9.0	15	600	0.25	0.1	10
MMSZ5245ET1	CC7	14.25	15	15.75	8.5	16	600	0.25	0.1	11
MMSZ5246ET1	CC8	15.20	16	16.80	7.8	17	600	0.25	0.1	12
MMSZ5248ET1	CD1	17.10	18	18.90	7.0	21	600	0.25	0.1	14
MMSZ5250ET1	CD3	19.00	20	21.00	6.2	25	600	0.25	0.1	15
MMSZ5252ET1	CD5	22.80	24	25.20	5.2	33	600	0.25	0.1	18
MMSZ5255ET1	CD8	26.60	28	29.40	4.5	44	600	0.25	0.1	21
MMSZ5256ET1	CD9	28.50	30	31.50	4.2	49	600	0.25	0.1	23
MMSZ5257ET1	CE1	31.35	33	34.65	3.8	58	700	0.25	0.1	25
MMSZ5263ET1	CE7	53.20	56	58.80	2.2	150	1300	0.25	0.1	43

4. The type numbers shown have a standard tolerance of $\pm 5\%$ on the nominal Zener voltage.
5. Nominal Zener voltage is measured with the device junction in thermal equilibrium at $T_L = 30^\circ\text{C} \pm 1^\circ\text{C}$.
6. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the ac current applied. The specified limits are for $I_{Z(AC)} = 0.1 I_{Z(dc)}$ with the AC frequency = 1 kHz.

MMSZ5221ET1 Series

TYPICAL CHARACTERISTICS

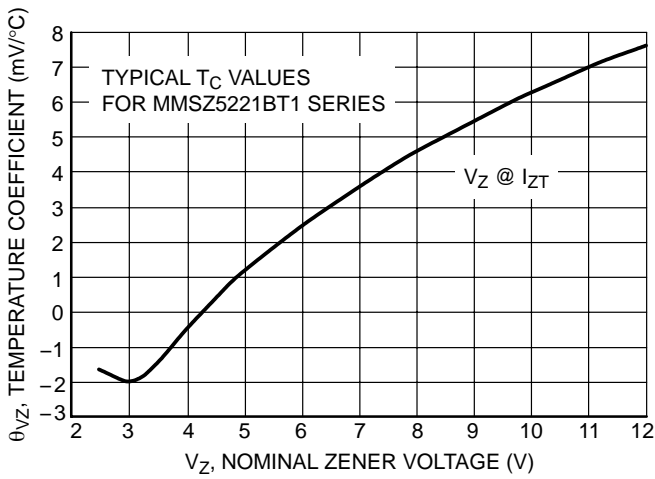


Figure 1. Temperature Coefficients (Temperature Range -55°C to +150°C)

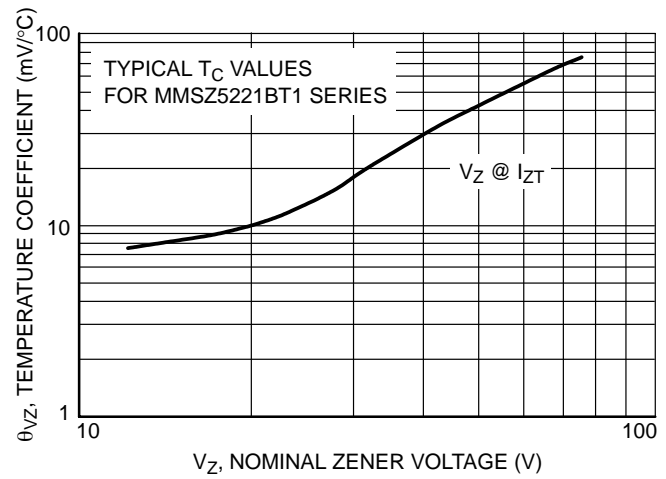


Figure 2. Temperature Coefficients (Temperature Range -55°C to +150°C)

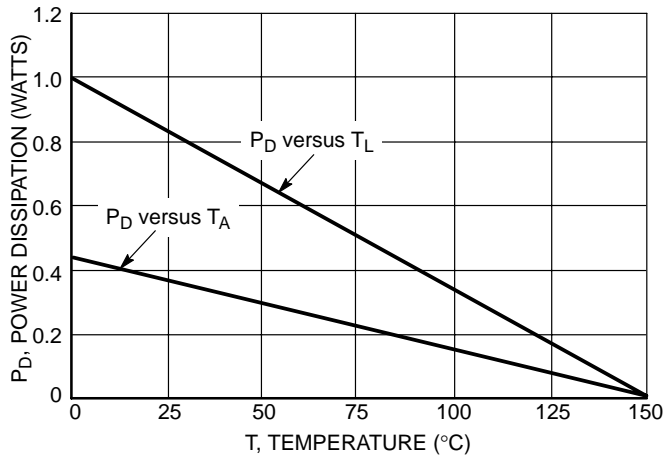


Figure 3. Steady State Power Derating

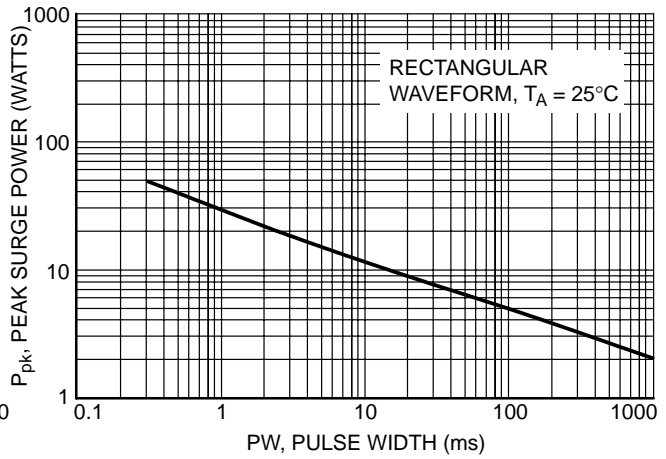


Figure 4. Maximum Nonrepetitive Surge Power

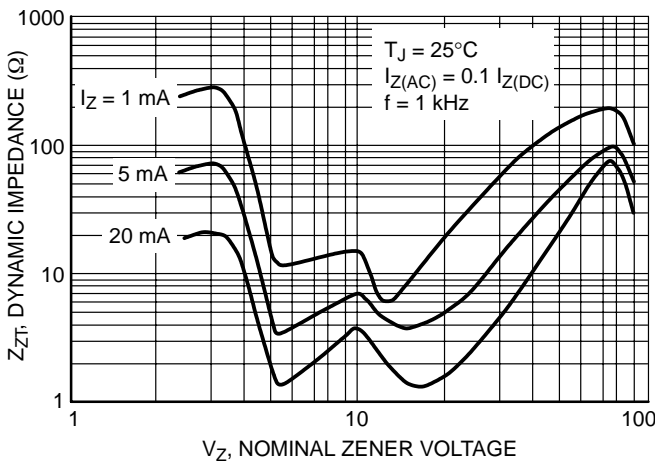


Figure 5. Effect of Zener Voltage on Zener Impedance

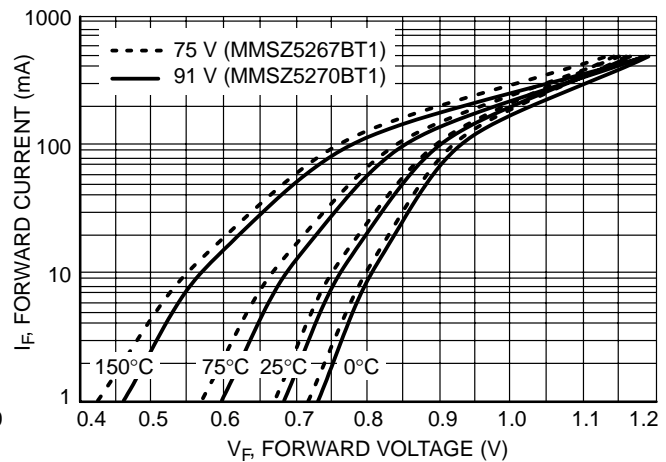


Figure 6. Typical Forward Voltage

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TYPICAL CHARACTERISTICS

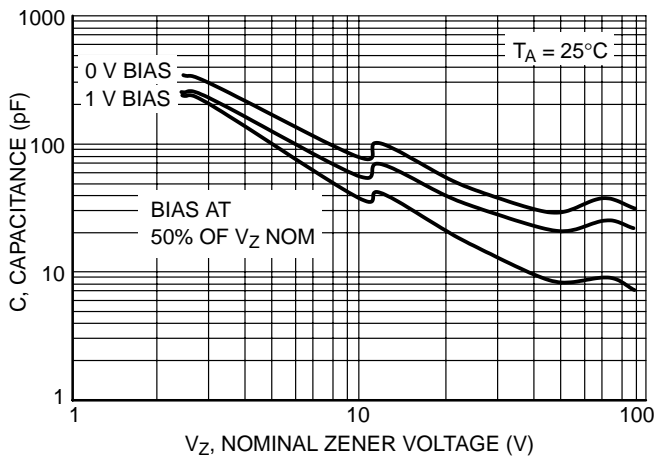


Figure 7. Typical Capacitance

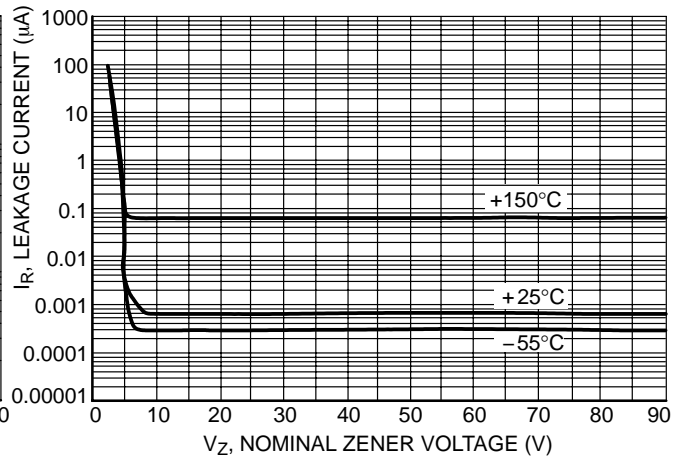


Figure 8. Typical Leakage Current

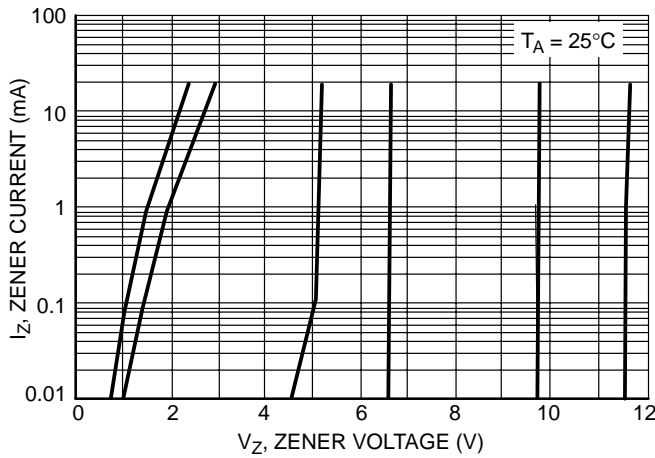


Figure 9. Zener Voltage versus Zener Current
(V_Z Up to 12 V)

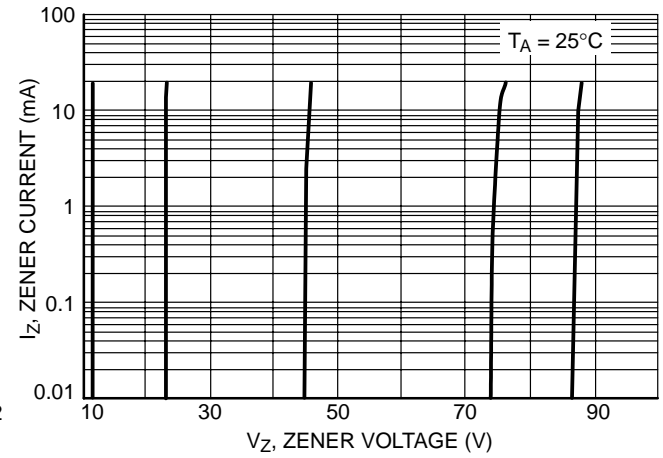


Figure 10. Zener Voltage versus Zener Current
(12 V to 91 V)

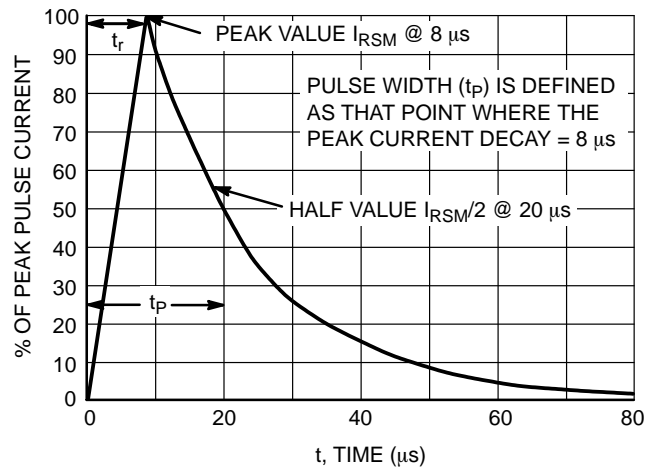
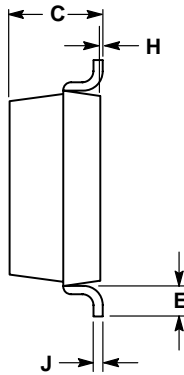
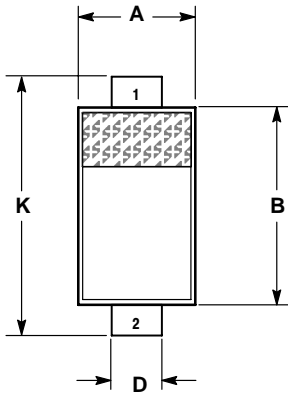


Figure 11. $8 \times 20 \mu\text{s}$ Pulse Waveform

MMSZ5221ET1 Series

PACKAGE DIMENSIONS

SOD-123
CASE 425-04
ISSUE C

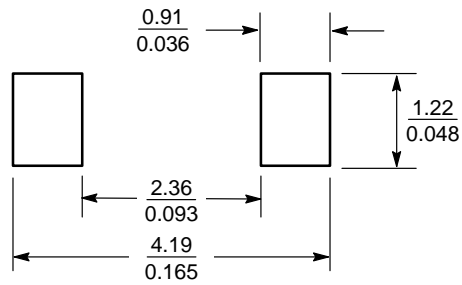


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.071	1.40	1.80
B	0.100	0.112	2.55	2.85
C	0.037	0.053	0.95	1.35
D	0.020	0.028	0.50	0.70
E	0.01	---	0.25	---
H	0.000	0.004	0.00	0.10
J	---	0.006	---	0.15
K	0.140	0.152	3.55	3.85

STYLE 1:
PIN 1. CATHODE
2. ANODE


SOLDERING FOOTPRINT*



SCALE 10:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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